



DGD1003

HALF-BRIDGE GATE DRIVER IN V-DFN3035-8

Description

Applications

DC-DC Converters

Class D Power Amplifiers

DC-AC Inverters AC-DC Power Supplies

Motor Controls

The DGD1003 is a high-voltage / high-speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half-bridge configuration. High voltage processing techniques enable the DGD1003's high side to switch to 150V in a bootstrap operation.

The DGD1003 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver output features high pulse current buffers designed for minimum driver cross conduction. The DGD1003 has a fixed internal deadtime of 420ns (typical).

The DGD1003 is offered in the V-DFN3035-8 package and operates over an extended -40°C to +125°C temperature range.

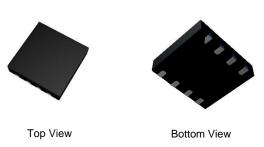
Features

- Floating High-Side Driver in Bootstrap Operation to 150V
- Drives Two N-Channel MOSFETs or IGBTs in a Half-Bridge Configuration
- 290mA Source/600mA Sink Output Current Capability
- Outputs Tolerant to Negative Transients
- Internal Dead Time of 420ns to Protect MOSFETs
- Wide Low Side Gate Driver Supply Voltage: 10V to 20V
- Logic Input (HIN and LIN*) 3.3V Capability
- Schmitt Triggered Logic Inputs
- Undervoltage Lockout for Vcc (Logic and Low Side Supply)
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: V-DFN3035-8
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish—NiPdAu
 Solderable per MIL-STD-202, Method 208(e4)
- Weight: 0.017 grams (Approximate)

V-DFN3035-8



Vcc Vc Vs HIN OGD1003 Vs COM LO Typical Configuration

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD1003FTA-13	DGD1003	13	12	5,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

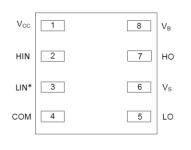
Marking Information



DGD1003 = Product Type Marking Code YY = Year (ex: 20 = 2020) WW = Week (01 to 53)



Pin Diagrams

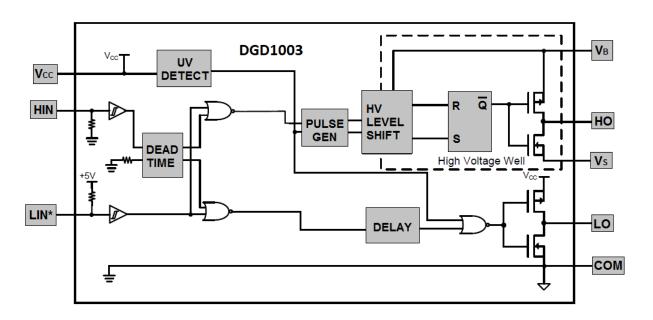


Top View: V-DFN3035-8

Pin Descriptions

Pin Number	Pin Name	Function	
1	Vcc	Logic and Low Side Supply	
2	HIN	Logic Input for High-Side Gate Driver Output in Phase with HO	
3	LIN*	Logic input for Low-Side Gate Driver Output out of Phase with LO	
4	COM	Low-Side and Logic Return	
5	LO	Low-Side Gate Drive Output	
6	Vs	High-Side Floating Supply Return	
7	HO	High-Side Gate Drive Output	
8	VB	High-Side Floating Supply	

Functional Block Diagram





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Supply Voltage	VB	-0.3 to +174	V
High-Side Floating Supply Offset Voltage	Vs	V _B -24 to V _B +0.3	V
High-Side Floating Output Voltage	Vно	Vs-0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dVs/dt	50	V/ns
Low-Side Fixed Supply Voltage	V _{CC}	-0.3 to +24	V
Low-Side Output Voltage	VLO	-0.3 to Vcc+0.3	V
Logic Input Voltage (HIN and LIN*)	Vin	-0.3 to Vcc+0.3	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	0.44	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	231	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	Tstg	-55 to +150]

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply Absolute Voltage	VB	Vs + 10	Vs + 20	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	150	V
High-Side Floating Output Voltage	Vно	Vs	VB	V
Low-Side Supply Voltage	Vcc	10	20	V
Low-Side Output Voltage	VLO	0	Vcc	V
Logic Input Voltage (HIN & LIN*)	VIN	0	5	V
Ambient Temperature	T _A	-40	+125	°C

Note: 6. Logic operation for V_S of -5V to +150V.



DC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, @T_A = +25°C, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" (HIN) & Logic "0" (LIN*) Input Voltage (Note 8)	Vін	2.5	_	_	V	V _{CC} = 10V to 20V
Logic "0" (HIN) & Logic "1" (LIN*) Input Voltage (Note 8)	VIL	—	_	0.8	V	Vcc = 10V to 20V
High Level Output Voltage, VBIAS - Vo	Vон	_	0.05	0.2	V	$I_0 = 2mA$
Low Level Output Voltage, Vo	Vol	—	0.02	0.1	V	$I_0 = 2mA$
Offset Supply Leakage Current	I _{LK}	—	_	50	μA	$V_{\rm B} = V_{\rm S} = 150 V$
Quiescent VBS Supply Current	IBSQ	_	60	100	μA	VIN = 0V or 5V
Quiescent V _{CC} Supply Current	lccq	—	350	500	μA	$V_{IN} = 0V \text{ or } 5V$
Logic "1" Input Bias Current	I _{IN+}	_	3	10	μA	$HIN = 5V, LIN^* = 0V$
Logic "0" Input Bias Current	lin-	—	_	5	μA	$HIN = 0V, LIN^* = 5V$
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}	8.0	8.9	9.8	V	—
Vcc Supply Undervoltage Negative Going Threshold	Vccuv-	7.4	8.2	9.0	V	—
Output High Short Circuit Pulsed Current	Io+	130	290	_	mA	Vo = 0V, PW ≤ 10µs
Output Low Short Circuit Pulsed Current	lo-	270	600	_	mA	Vo = 15V, PW ≤ 10µs

Notes: 7. The V_{IN} and I_{IN} parameters are applicable to the two logic pins: HIN and LIN*. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.

8. For optimal operation, it is recommended that the input pulses (HIN and LIN*) should have a minimum amplitude of 2.5V with a minimum pulse width of 840ns.

AC Electrical Characteristics (VBIAS (VCC, VBS) = 15V, CL = 1000pF, @TA = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	ton	—	680	820	ns	$V_S = 0V$
Turn-Off Propagation Delay	tOFF	_	150	220	ns	V _S = 150V
Delay Matching, HO & LO Turn-On/Turn-Off	tdм	—	—	60	ns	—
Turn-On Rise Time	tr	—	70	170	ns	Vs = 0V
Turn-Off Fall Time	t _f	_	35	90	ns	$V_S = 0V$
Deadtime: tDT LO-HO & tDT HO-LO	tdт	300	420	650	ns	—



Timing Waveforms

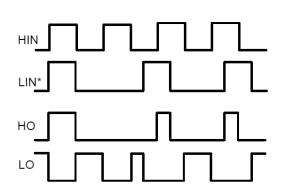
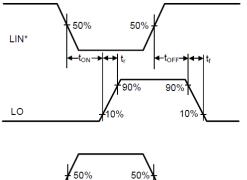


Figure 1. Input / Output Timing Diagram



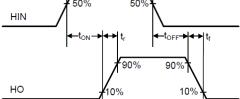


Figure 2. Switching Time Waveform Definitions

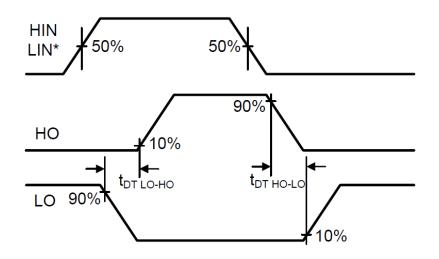


Figure 3. Deadtime Waveform Definitions



Typical Performance Characteristics (Vcc = 15V, @TA = +25°C, unless otherwise specified.)

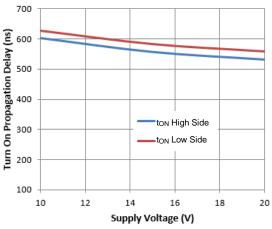


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

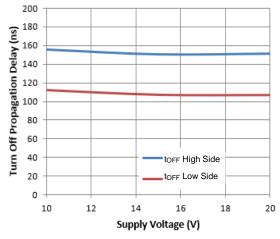


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

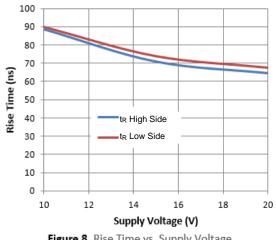


Figure 8. Rise Time vs. Supply Voltage

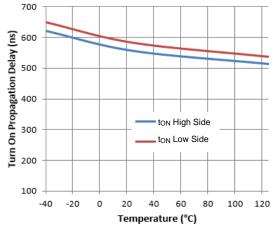


Figure 5. Turn-on Propagation Delay vs. Temperature

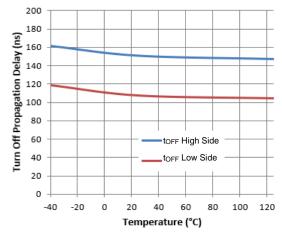
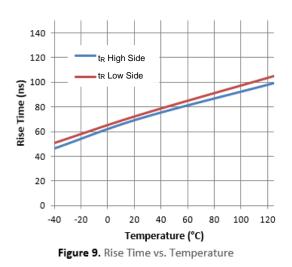
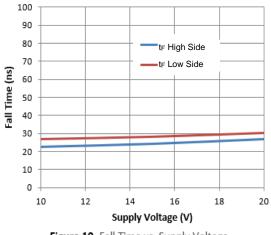


Figure 7. Turn-off Propagation Delay vs. Temperature





Typical Performance Characteristics (continued)





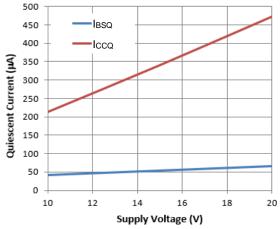
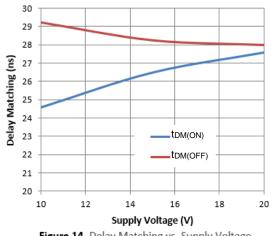
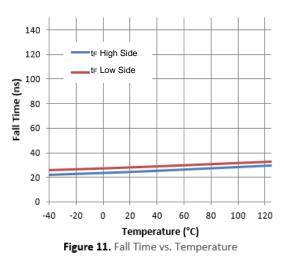
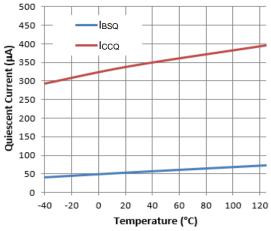


Figure 12. Quiescent Current vs. Supply Voltage

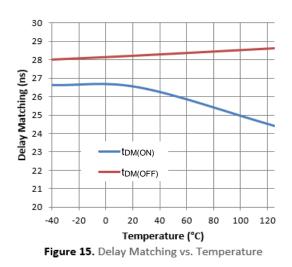














Typical Performance Characteristics (continued)

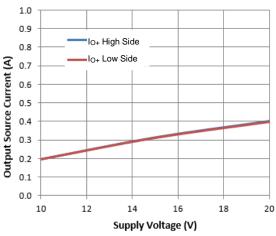


Figure 16. Output Source Current vs. Supply Voltage

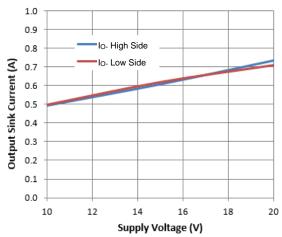


Figure 18. Output Sink Current vs. Supply Voltage

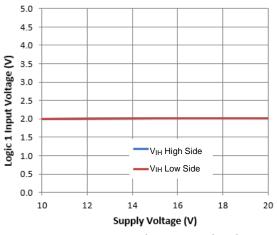


Figure 20. Logic 1 Input Voltage vs. Supply Voltage

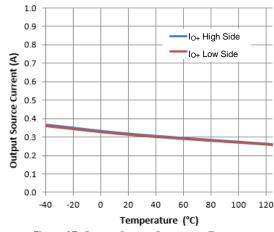
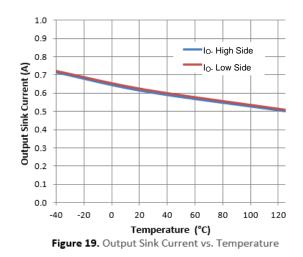


Figure 17. Output Source Current vs. Temperature



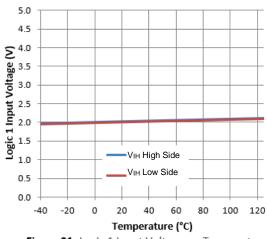


Figure 21. Logic 1 Input Voltage vs. Temperature



Typical Performance Characteristics (continued)

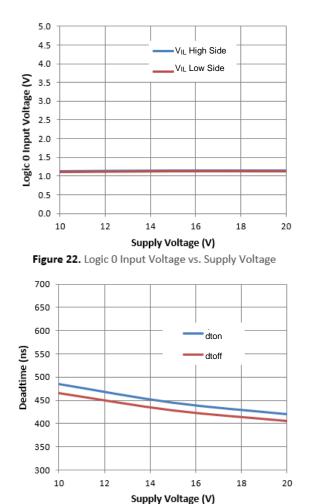
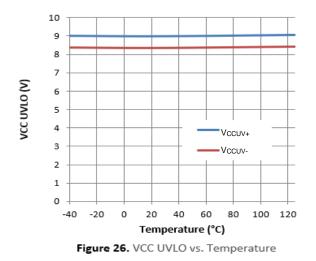
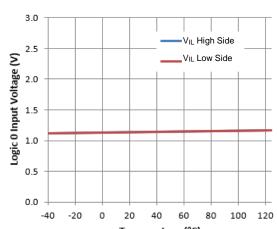
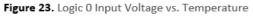


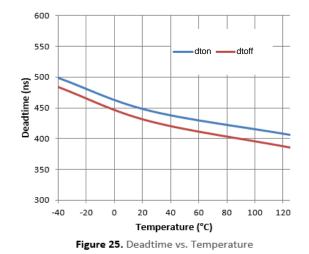
Figure 24. Deadtime vs. Supply Voltage





Temperature (°C)





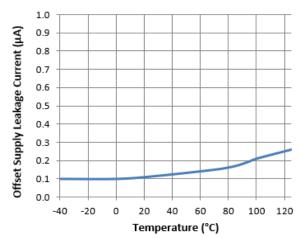
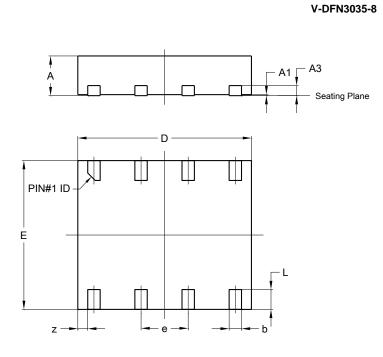


Figure 27. Offset Supply Leakage Current vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

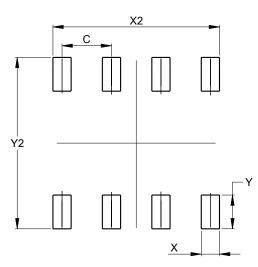


	V-DFN3035-8						
Dim	Min	Max	Тур				
Α	0.75	0.85	0.80				
A1	0.00	0.05	0.03				
A3	0.203 REF						
b	0.20	0.30	0.25				
D	3.45	3.55	3.50				
Е	2.95	3.05	3.00				
е			0.95				
L	0.35	0.45	0.40				
z			0.20				
All	All Dimensions in mm						

Suggested Pad Layout

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Please see http://www.diodes.com/package-outlines.html for the latest version.



V-DFN3035-8

Dimensions	Value (in mm)
С	0.95
Х	0.35
X2	3.20
Y	0.65
Y2	3.30



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